

## Supporting Information

### Fabrication of Bi<sub>2</sub>S<sub>3</sub>/ZnO heterostructures: An excellent photocatalyst for visible-light-driven hydrogen generation and photoelectrochemical properties

Susmita Bera, Srabanti Ghosh, Rajendra N. Basu

CSIR-Central Glass and Ceramic Research Institute,  
196, Raja S.C. Mullick Road, Kolkata- 700032, India

E-mail: [ghosh.srabanti@gmail.com](mailto:ghosh.srabanti@gmail.com), [rnbasu@cgcri.res.in](mailto:rnbasu@cgcri.res.in)

#### List of experiments:

Fig. S1. XRD patterns of M-Bi<sub>2</sub>S<sub>3</sub> at three different reaction times as 10 hours, 16 hours and 24 hours.

Fig. S2. TEM image of ZnO nanoparticles.

Fig. S3. N<sub>2</sub> adsorption-desorption isotherm of bare M-Bi<sub>2</sub>S<sub>3</sub> and M-Bi<sub>2</sub>S<sub>3</sub>/ZnO heterostructure.

Fig. S4. Photocatalytic MO degradation in presence of catalyst, bare semiconductors L-Bi<sub>2</sub>S<sub>3</sub>, M-Bi<sub>2</sub>S<sub>3</sub> and heterostructure L-Bi<sub>2</sub>S<sub>3</sub>/ZnO, M-Bi<sub>2</sub>S<sub>3</sub>/ZnO under UV light irradiation.

Fig. S5. Current-Voltage curve of bare M-Bi<sub>2</sub>S<sub>3</sub> and (b) M-Bi<sub>2</sub>S<sub>3</sub>/ZnO heterostructure without light (dark) and with irradiation at a fixed bias voltage of 500 mV.

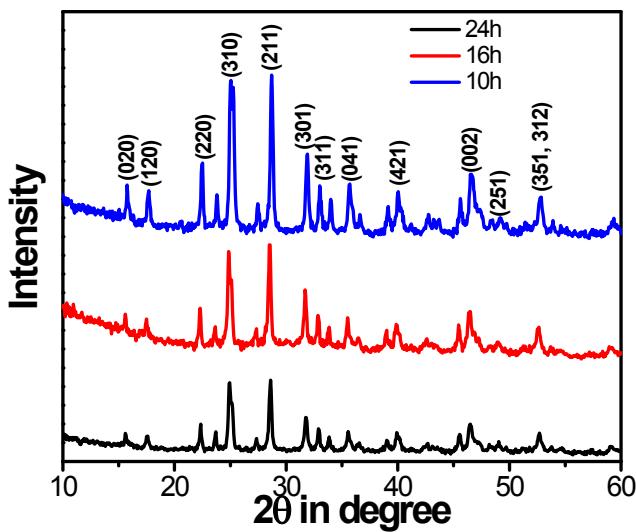


Fig. S1 XRD patterns of M-Bi<sub>2</sub>S<sub>3</sub> at three different reaction times as 10 hours, 16 hours and 24 hours.

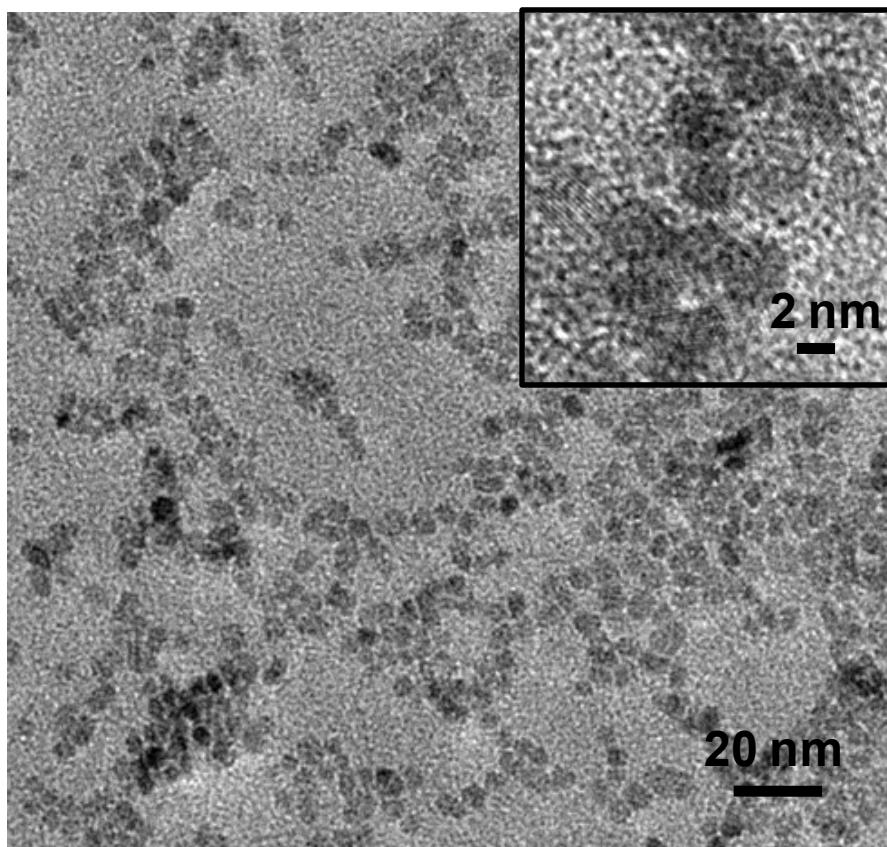


Fig. S2 TEM image of ZnO nanoparticles.

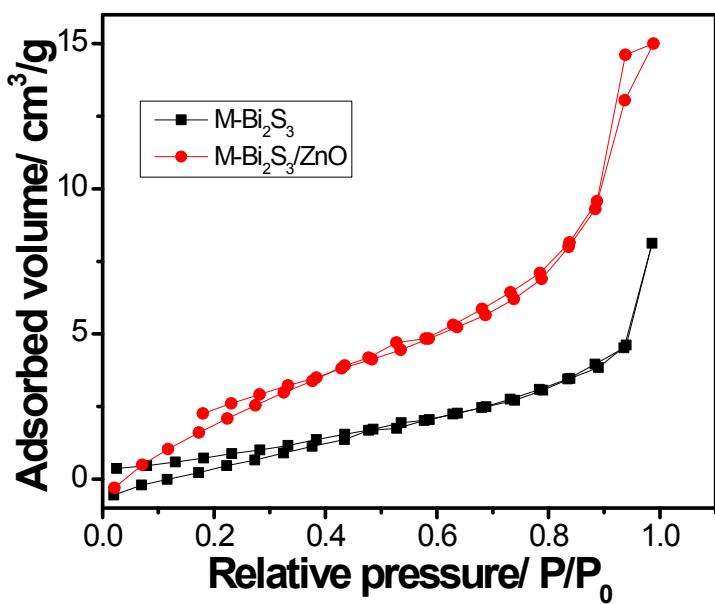


Fig. S3 N<sub>2</sub> adsorption-desorption isotherm of bare M-Bi<sub>2</sub>S<sub>3</sub> and M-Bi<sub>2</sub>S<sub>3</sub>/ZnO heterostructure.

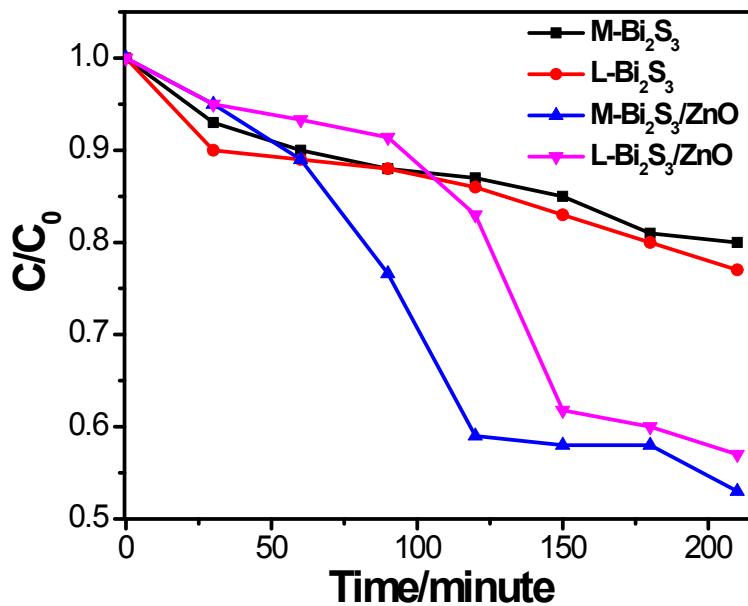


Fig. S4 Photocatalytic MO degradation in presence of catalyst, bare semiconductors L-Bi<sub>2</sub>S<sub>3</sub>, M-Bi<sub>2</sub>S<sub>3</sub> and heterostructure L-Bi<sub>2</sub>S<sub>3</sub>/ZnO, M-Bi<sub>2</sub>S<sub>3</sub>/ZnO under UV light irradiation.

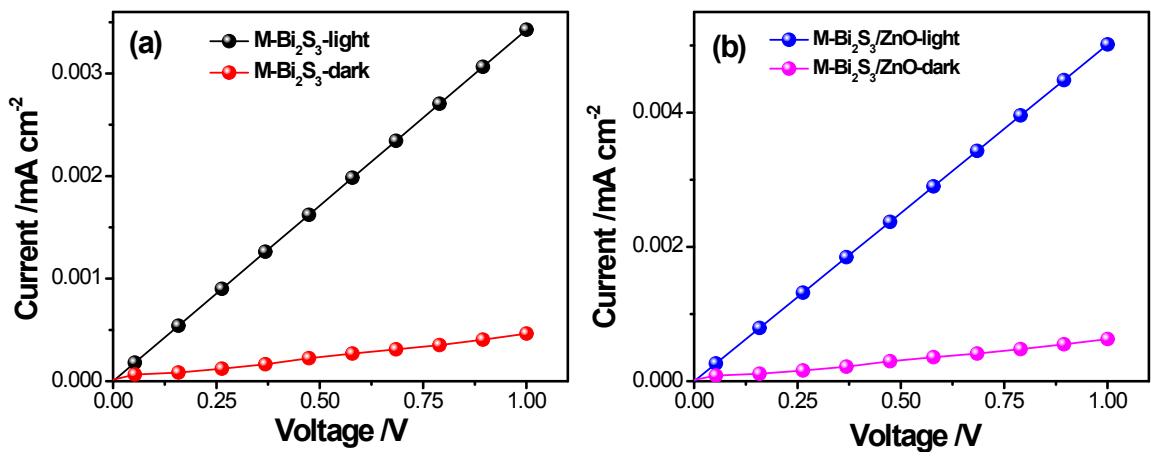


Fig. S5 Current-Voltage curve of bare M-Bi<sub>2</sub>S<sub>3</sub> and (b) heterostructure M-Bi<sub>2</sub>S<sub>3</sub>/ZnO without light (dark) and with irradiation at a fixed bias voltage of 500 mV.